

## HIGH VOLTAGE ULTRAFAST RECTIFIER

### MAIN PRODUCT CHARACTERISTICS

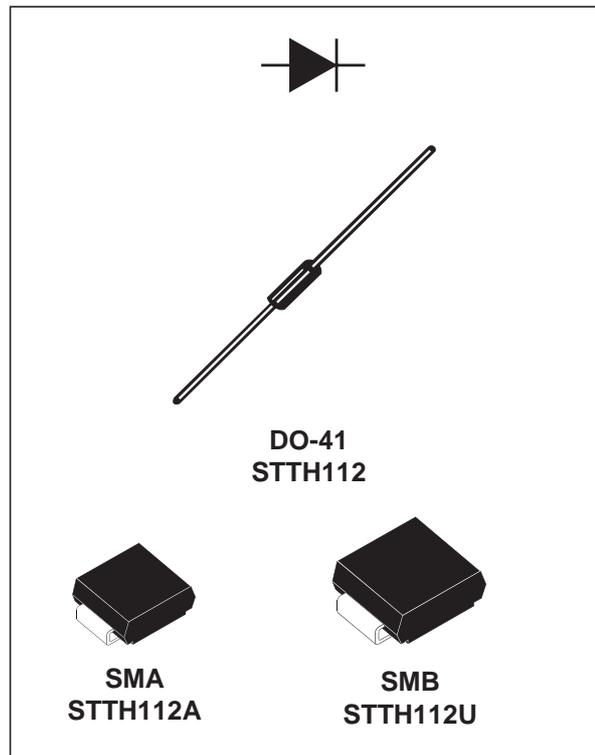
$I_{F(AV)}$	1 A
$V_{RRM}$	1200 V
$T_j(\text{max})$	175 °C
$V_F(\text{max})$	1.65 V

### FEATURES AND BENEFITS

- Low forward voltage drop
- High reliability
- High surge current capability
- Soft switching for reduced EMI disturbances
- Planar technology

### DESCRIPTION

The STTH112, which is using ST ultrafast high voltage planar technology, is specially suited for free-wheeling, clamping, snubbing, demagnetization in power supplies and other power switching applications.



### ABSOLUTE RATINGS (limiting values)

Symbol	Parameter			Value	Unit
$V_{RRM}$	Repetitive peak reverse voltage			1200	V
$V_{(RMS)}$	RMS voltage			850	V
$I_{F(AV)}$	Average forward current	$T_I = 85^\circ\text{C}$ $\delta = 0.5$	DO-41	1	A
		$T_I = 115^\circ\text{C}$ $\delta = 0.5$	SMA		
		$T_I = 125^\circ\text{C}$ $\delta = 0.5$	SMB		
$I_{FSM}$	Forward surge current $t = 8.3$ ms	DO-41		20	A
		SMA		18	
		SMB			
$T_{stg}$	Storage temperature range			- 50 + 175	°C
$T_j$	Maximum operating junction temperature			+ 175	°C

**THERMAL PARAMETERS**

Symbol	Parameter			Value	Unit
R <sub>th(j-l)</sub>	Junction to lead	L = 10 mm	DO-41	45	°C/W
			SMA	30	
			SMB	25	
R <sub>th(j-a)</sub>	Junction to ambient	L = 10 mm	DO-41	110	

**STATIC ELECTRICAL CHARACTERISTICS**

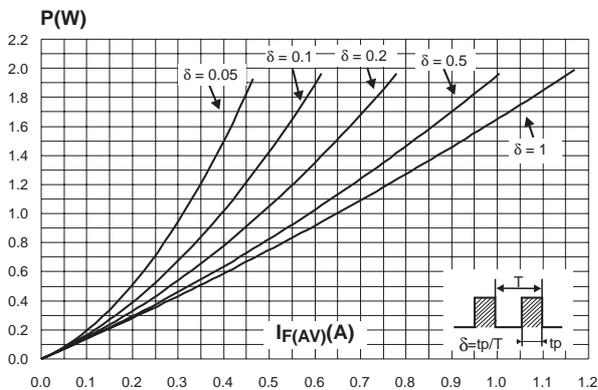
Symbol	Parameter	Tests conditions		Min.	Typ.	Max.	Unit
I <sub>R</sub>	Reverse leakage current	V <sub>R</sub> = 1200V	T <sub>j</sub> = 25°C			5	µA
			T <sub>j</sub> = 125°C			50	
V <sub>F</sub>	Forward voltage drop	I <sub>F</sub> = 1 A	T <sub>j</sub> = 25°C			1.9	V
			T <sub>j</sub> = 125°C		1.17	1.65	

To evaluate the maximum conduction losses use the following equation :  
 $P = 1.35 \times I_{F(AV)} + 0.3 \times I_{F(RMS)}^2$

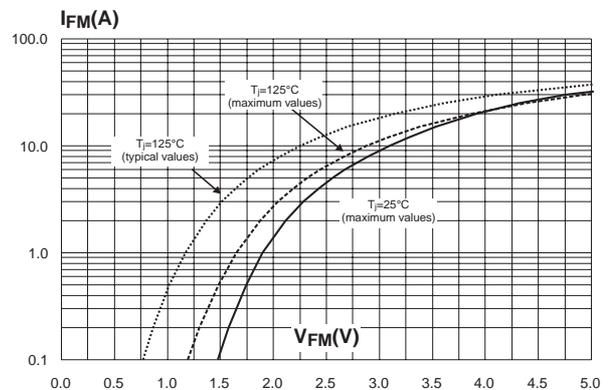
**DYNAMIC ELECTRICAL CHARACTERISTICS**

Symbol	Parameter	Tests conditions		Min.	Typ.	Max.	Unit
t <sub>rr</sub>	Reverse recovery time	I <sub>F</sub> = 0.5 A I <sub>rr</sub> = 0.25 A I <sub>R</sub> = 1A	T <sub>j</sub> = 25°C			75	ns
t <sub>fr</sub>	Forward recovery time	I <sub>F</sub> = 1 A dI <sub>F</sub> /dt = 50 A/µs V <sub>FR</sub> = 1.1 x V <sub>Fmax</sub>	T <sub>j</sub> = 25°C			500	ns
V <sub>FP</sub>	Forward recovery voltage						30

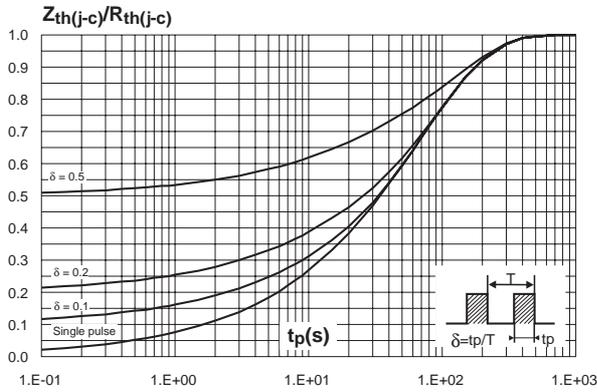
**Fig. 1:** Conduction losses versus average current.



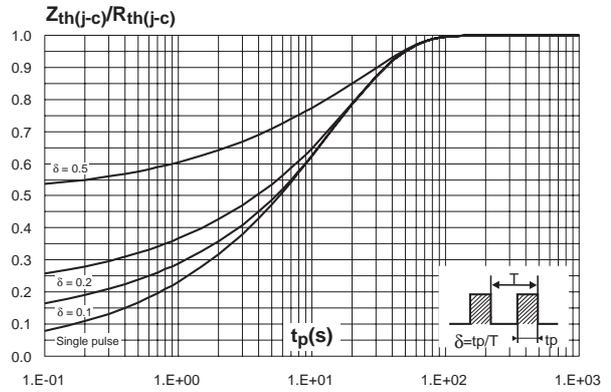
**Fig. 2:** Forward voltage drop versus forward current.



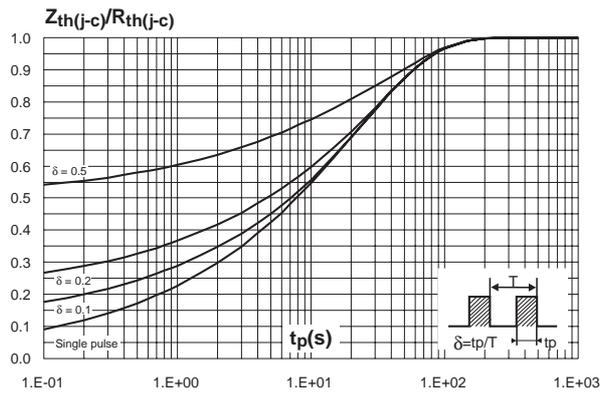
**Fig. 3-1:** Relative variation of thermal impedance junction ambient versus pulse duration (epoxy FR4,  $L_{leads} = 10\text{mm}$ ) (DO-41).



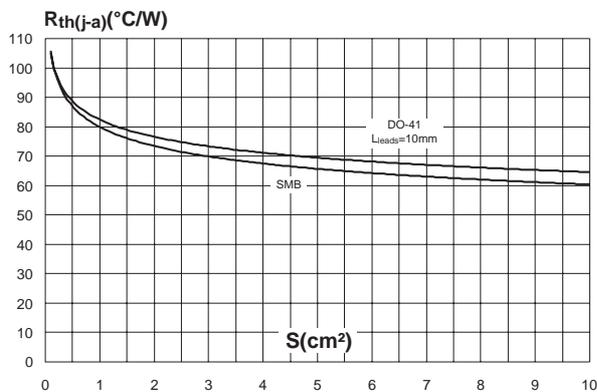
**Fig. 3-2:** Relative variation of thermal impedance junction ambient versus pulse duration (epoxy FR4) (SMA).



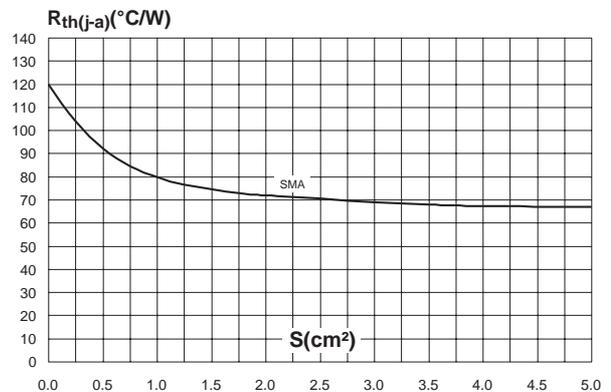
**Fig. 3-3:** Relative variation of thermal impedance junction ambient versus pulse duration (epoxy FR4)(SMB).



**Fig. 4-1:** Thermal resistance junction to ambient versus copper surface under each lead (epoxy printed circuit board FR4, copper thickness:  $35\mu\text{m}$ ) (DO-41, SMB).



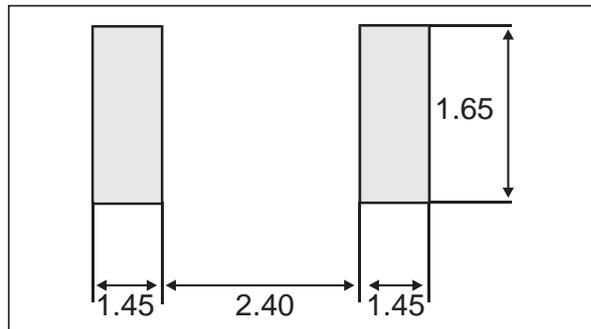
**Fig. 4-2:** Thermal resistance junction to ambient versus copper surface under each lead (epoxy printed circuit board FR4, copper thickness:  $35\mu\text{m}$ ) (SMA).



**PACKAGE MECHANICAL DATA**  
SMA

REF.	DIMENSIONS			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A1	1.90	2.70	0.075	0.106
A2	0.05	0.20	0.002	0.008
b	1.25	1.65	0.049	0.065
c	0.15	0.41	0.006	0.016
E	4.80	5.60	0.189	0.220
E1	3.95	4.60	0.156	0.181
D	2.25	2.95	0.089	0.116
L	0.75	1.60	0.030	0.063

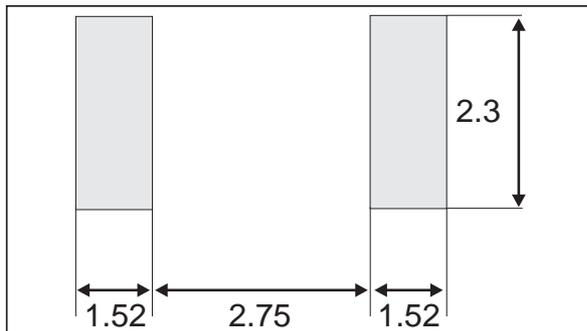
**FOOTPRINT (in millimeters)**



**PACKAGE MECHANICAL DATA**  
SMB

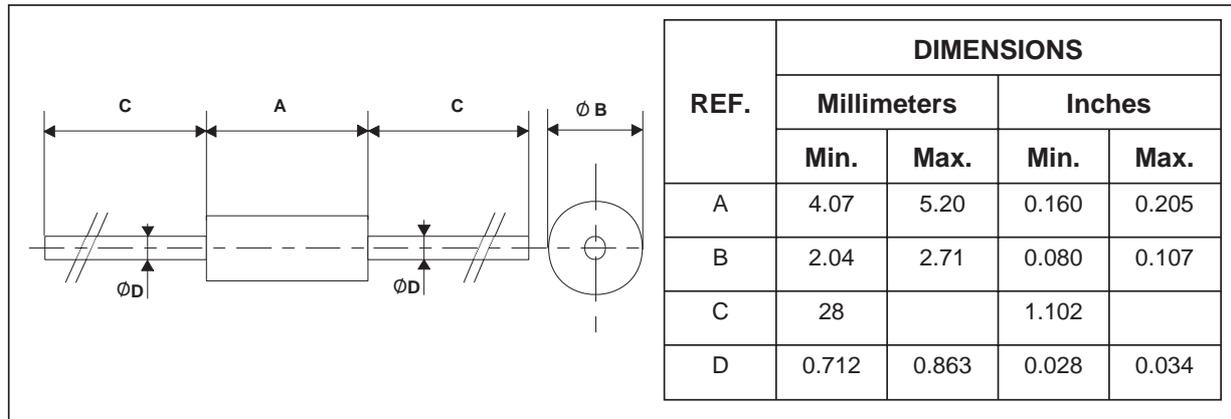
REF.	DIMENSIONS			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A1	1.90	2.45	0.075	0.096
A2	0.05	0.20	0.002	0.008
b	1.95	2.20	0.077	0.087
c	0.15	0.41	0.006	0.016
E	5.10	5.60	0.201	0.220
E1	4.05	4.60	0.159	0.181
D	3.30	3.95	0.130	0.156
L	0.75	1.60	0.030	0.063

**FOOTPRINT (in millimeters)**



# STTH112/A/U

## PACKAGE MECHANICAL DATA DO-41



Ordering code	Marking	Package	Weight	Base qty	Delivery mode
STTH112	STTH112	DO-41	0.34 g	2000	Ammopack
STTH112A	H12	SMA	0.068 g	5000	Tape & reel
STTH112U	U12	SMB	0.11 g	2500	Tape & reel
STTH112RL	STTH112	DO-41	0.34 g	5000	Tape & reel

- Epoxy meets UL 94,V0

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